

N-Channel 100-V (D-S) MOSFET

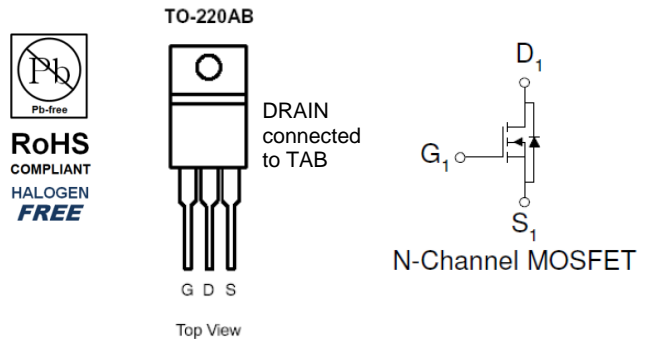
Key Features:

- Low $r_{DS(on)}$ trench technology
- Low thermal impedance
- Fast switching speed

Typical Applications:

- White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY		
V_{DS} (V)	$r_{DS(on)}$ (m Ω)	I_D (A)
100	44 @ $V_{GS} = 10V$	70 ^a
	64 @ $V_{GS} = 4.5V$	



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

Parameter	Symbol	Limit	Units
Drain-Source Voltage	V_{DS}	100	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current ^a	I_D	70	A
Pulsed Drain Current ^b	I_{DM}	280	A
Continuous Source Current (Diode Conduction) ^a	I_S	70	A
Power Dissipation ^a	P_D	300	W
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55 to 175	$^\circ\text{C}$

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Maximum	Units
Maximum Junction-to-Ambient ^a	$R_{\theta JA}$	62.5	$^\circ\text{C/W}$
		0.5	

Notes

- Surface Mounted on 1" x 1" FR4 Board.
- Pulse width limited by maximum junction temperature

Electrical Characteristics

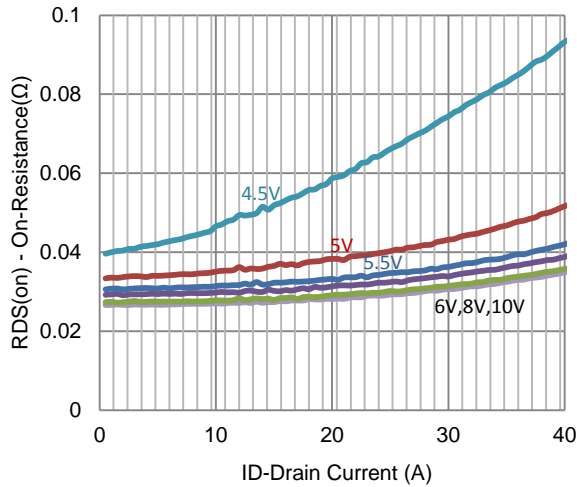
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static						
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1			V
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 80 V, V_{GS} = 0 V$			1	uA
		$V_{DS} = 80 V, V_{GS} = 0 V, T_J = 55^\circ C$			25	
On-State Drain Current	$I_{D(on)}$	$V_{DS} = 5 V, V_{GS} = 10 V$	140			A
Drain-Source On-Resistance	$r_{DS(on)}$	$V_{GS} = 10 V, I_D = 20 A$			44	m Ω
		$V_{GS} = 4.5 V, I_D = 20 A$			64	
Forward Transconductance	g_{fs}	$V_{DS} = 15 V, I_D = 20 A$		20		S
Diode Forward Voltage	V_{SD}	$I_S = 35 A, V_{GS} = 0 V$		1		V
Dynamic						
Total Gate Charge	Q_g	$V_{DS} = 50 V, V_{GS} = 5.5 V,$ $I_D = 20 A$		22		nC
Gate-Source Charge	Q_{gs}			7.3		
Gate-Drain Charge	Q_{gd}			14		
Turn-On Delay Time	$t_{d(on)}$	$V_{DS} = 50 V, R_L = 2.5 \Omega,$ $I_D = 20 A,$ $V_{GEN} = 10 V, R_{GEN} = 6 \Omega$		9		ns
Rise Time	t_r			13		
Turn-Off Delay Time	$t_{d(off)}$			44		
Fall Time	t_f			16		
Input Capacitance	C_{iss}	$V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz$		1318		pF
Output Capacitance	C_{oss}			147		
Reverse Transfer Capacitance	C_{rss}			143		

Notes

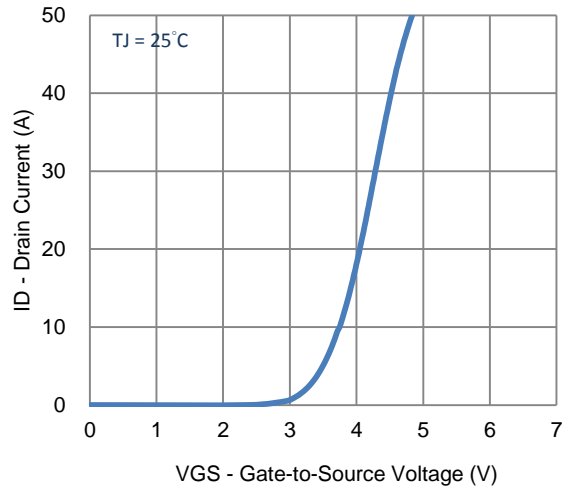
- Pulse test: $PW \leq 300 \mu s$ duty cycle $\leq 2\%$.
- Guaranteed by design, not subject to production testing.

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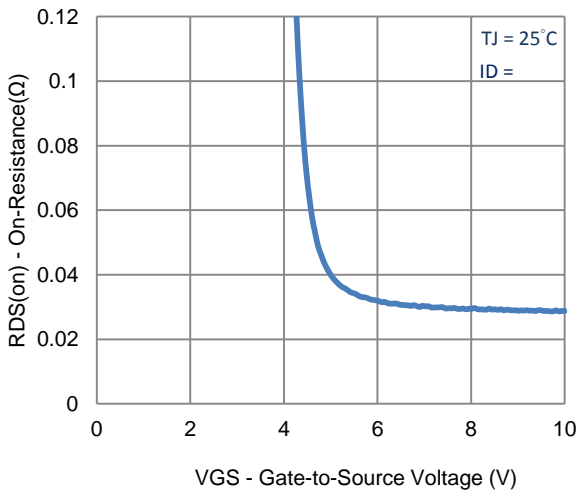
Typical Electrical Characteristics



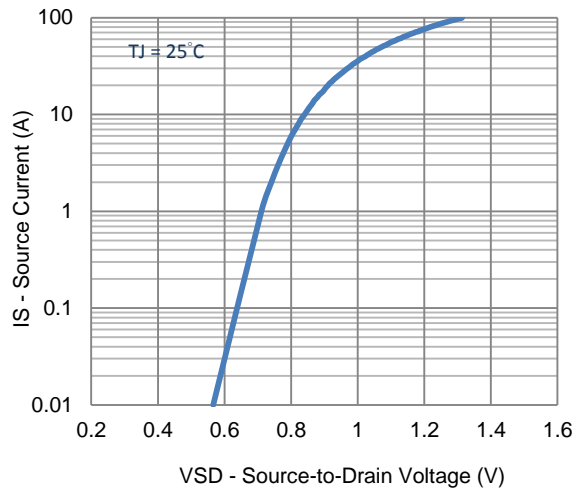
1. On-Resistance vs. Drain Current



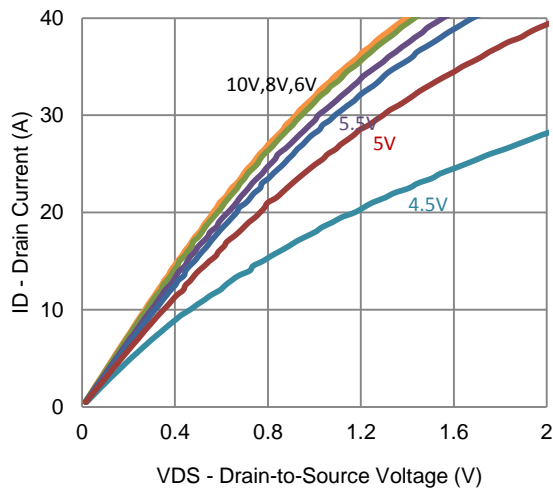
2. Transfer Characteristics



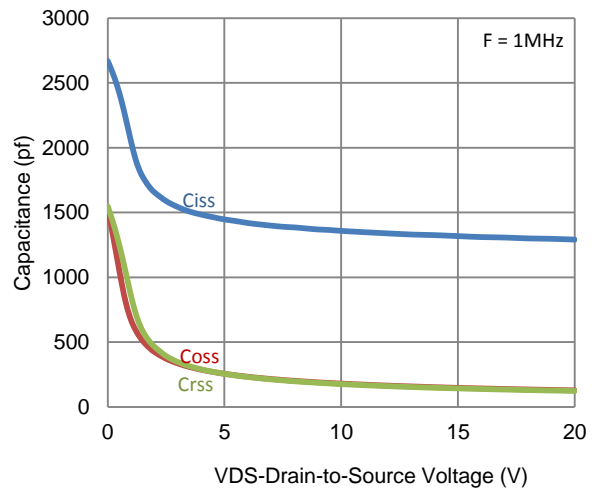
3. On-Resistance vs. Gate-to-Source Voltage



4. Drain-to-Source Forward Voltage

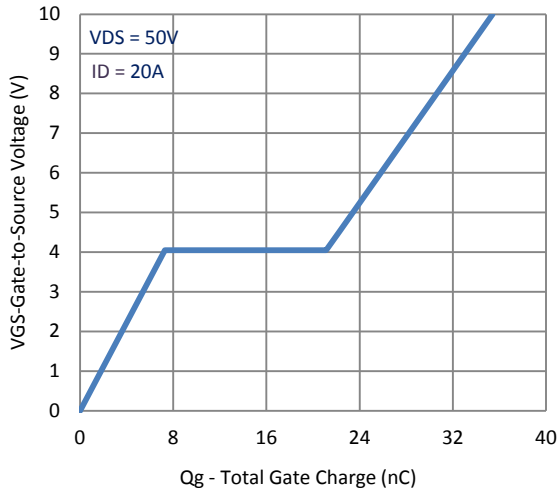


5. Output Characteristics

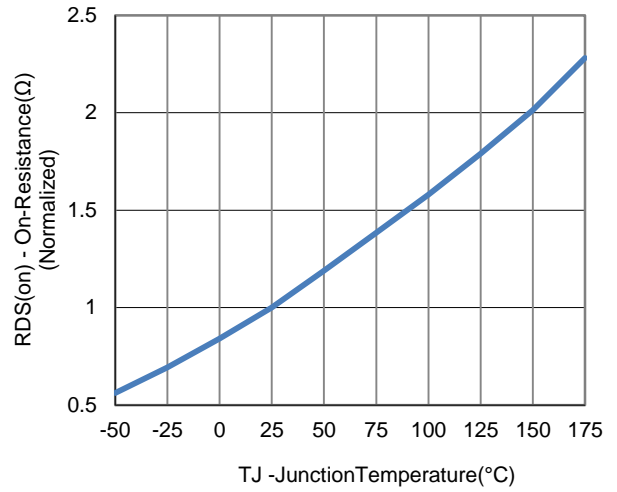


6. Capacitance

Typical Electrical Characteristics

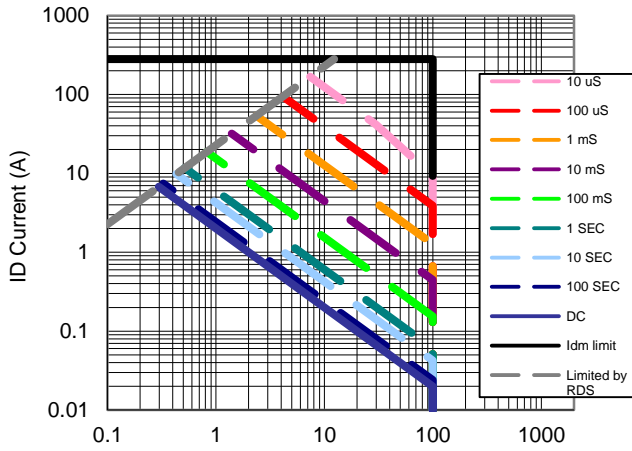


7. Gate Charge

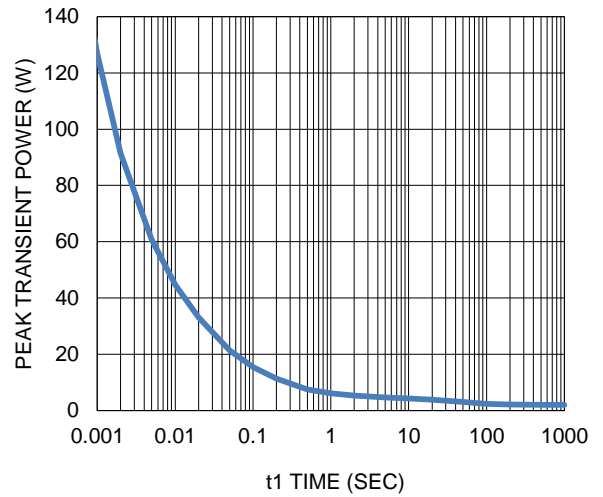


8. Normalized On-Resistance Vs Junction Temperature

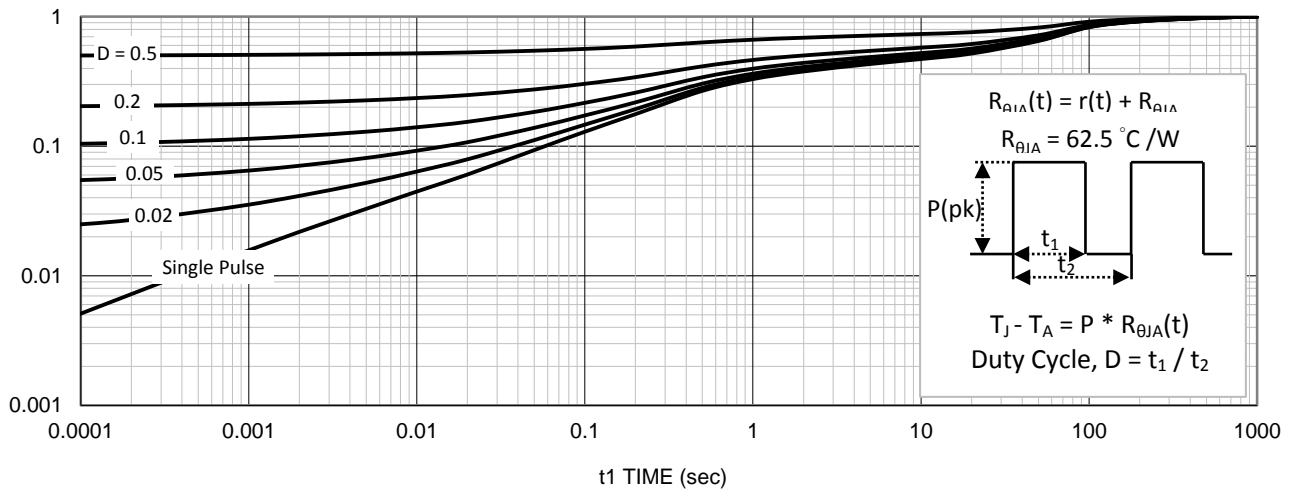
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9. Safe Operating Area



10. Single Pulse Maximum Power Dissipation



11. Normalized Thermal Transient Junction to Ambient

Package Information

